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P-Channel 1.8V Specified PowerTrench[®] MOSFET

General Description

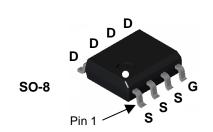
This P-Channel 1.8V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (1.8V - 8V).

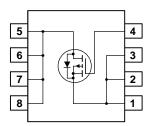
Applications

- Power management
- Load switch
- Battery protection

Features

- -13.5 A, -20 V. $R_{DS(ON)} = 8.5 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$ $R_{DS(ON)} = 10.5 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$ $R_{DS(ON)} = 14 \text{ m}\Omega @ V_{GS} = -1.8 \text{ V}$
- · Fast switching speed
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High current and power handling capability





Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Source	rce Voltage		-20	V
V _{GSS}	Gate-Sourc	e Voltage		±8	V
l _D	Drain Curre	nt – Continuous	(Note 1a)	-13.5	A
		 Pulsed 		-50	
PD	Power Dissipation for Single Operation (N		n (Note 1a)	2.5	W
			(Note 1b)	1.5	
			(Note 1c)	1.2	
Tj, T _{stg}	Operating and Storage Junction Temperature Range			-55 to +175	
Therma	I Charac				
R _{θJA}	Thermal Re	hermal Resistance, Junction-to-Ambient (Note 1a)		50	°C/W
R _{θJA}	Thermal Re	Thermal Resistance, Junction-to-Ambient (Note 1c)		125	°C/W
R _{eJC}	Thermal Resistance, Junction-to-Case (Note 1)			25 °C	
Packag	e Markin	g and Ordering I	nformation		
Device Marking		- Device	Reel Size	Tape width	Quantity
•	Marking	Device	Reel Size	Tape width	Quantity

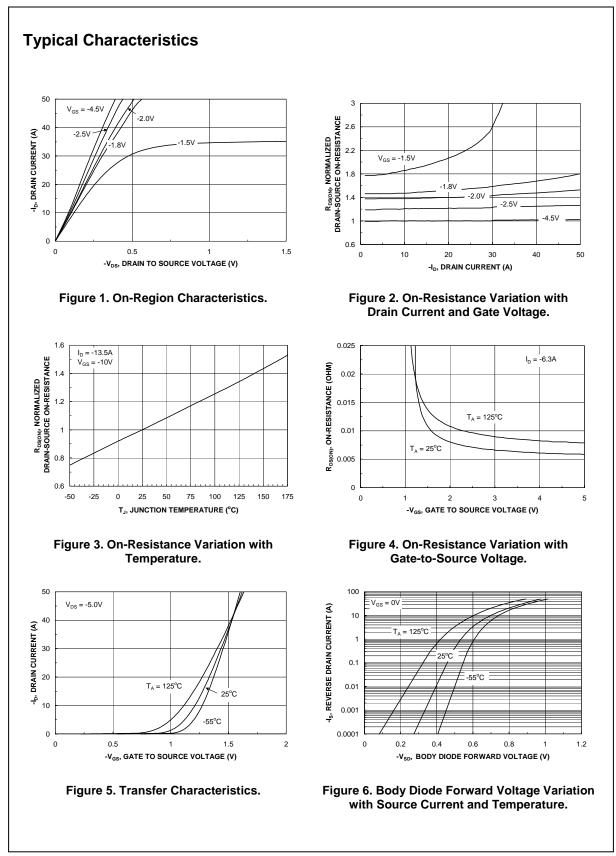
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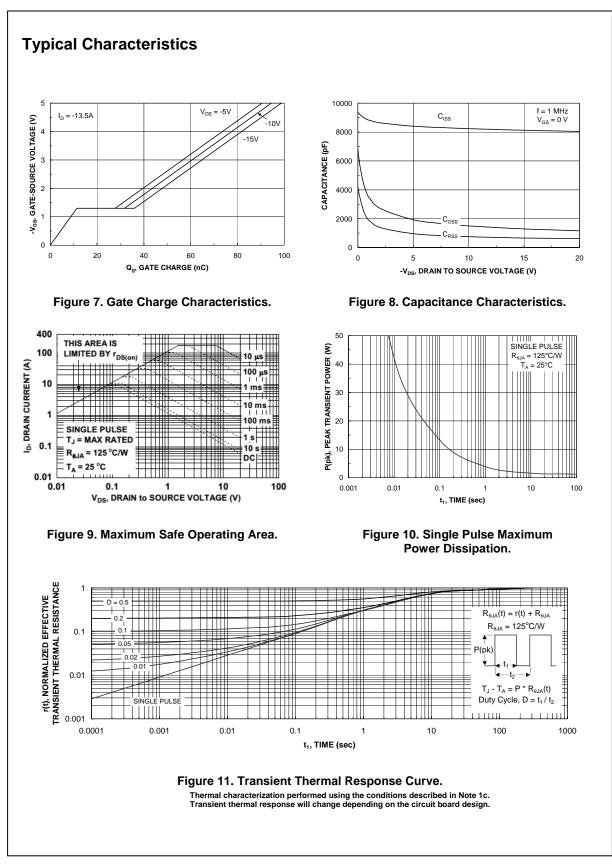
FDS4465

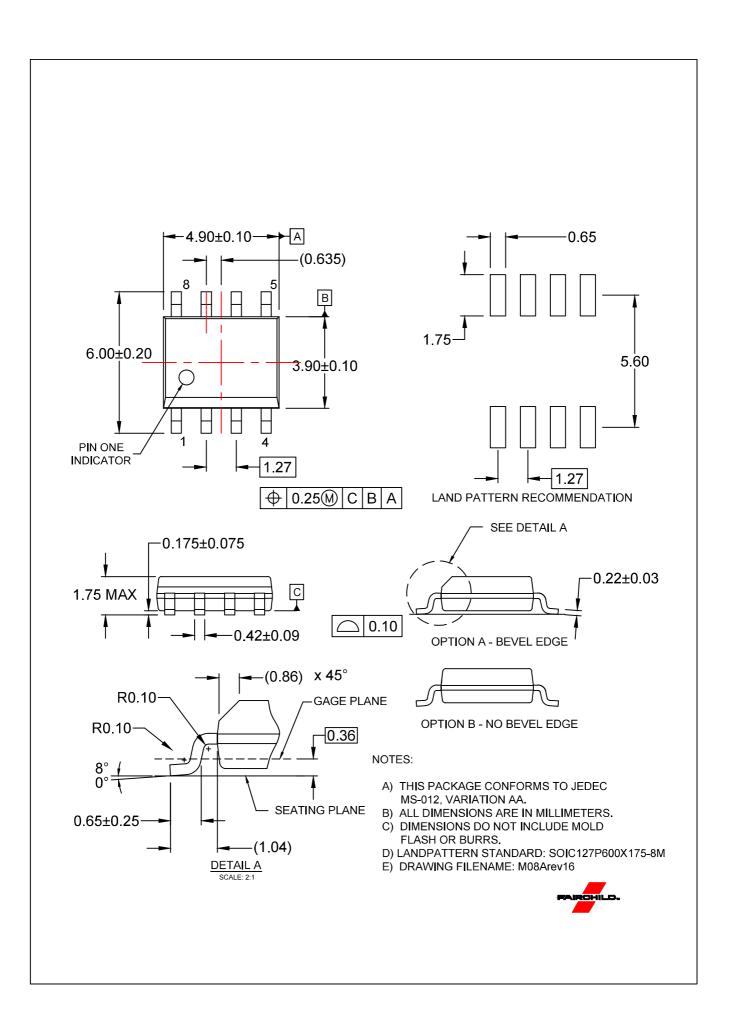
September 2014

	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics				•	
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-12		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
I _{GSSF}	Gate–Body Leakage, Forward	$V_{GS} = 8 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate–Body Leakage, Reverse	$V_{GS} = -8 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.4	-0.6	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS}=-4.5 \ V, I_D=-13.5 \ A \\ V_{GS}=-2.5 \ V, I_D=-12 \ A \\ V_{GS}=-1.8 \ V, I_D=-10.5 \ A \\ V_{GS}=-4.5 \ V, \ I_D=-13.5A, \ T_J=125^\circ C \end{array} $		6.7 8.0 9.8 9.0	8.5 10.5 14 13	mΩ
I _{D(on)}	On-State Drain Current	$V_{GS} = -4.5 V$, $V_{DS} = -5 V$	-50			Α
g _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_D = -13.5 A$		70		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			8237		pF
Coss	Output Capacitance	f = 1.0 MHz		1497		, pF
C _{rss}	Reverse Transfer Capacitance			750		pF
R _g	Gate Resistance		0.1	3.0	6.0	Ω
-	g Characteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time	$V_{DD} = -10V, \qquad I_D = -1 A,$		20	36	ns
t _r	Turn–On Rise Time	$V_{\text{GS}} = -4.5 \text{ V}, \qquad R_{\text{GEN}} = 6 \Omega$		24	38	ns
t _{d(off)}	Turn–Off Delay Time	-		300	480	ns
t _f	Turn–Off Fall Time			140	224	ns
Qg	Total Gate Charge	$V_{DS} = -10 \text{ V}, \qquad I_D = -13.5 \text{ A},$		86	120	nC
Q _{qs}	Gate–Source Charge	$V_{GS} = -4.5 V$		20	-	nC
Q _{gd}	Gate–Drain Charge	1		11		nC
-	ource Diode Characteristics	and Maximum Patings	1	1	1	1
ls	Maximum Continuous Drain–Source				-2.1	А
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = -2.1 \text{ A} (\text{Note 2})$		-0.6	-1.2	V

2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%









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